

### 1050 nm Booster Optical Amplifier



#### **Description**

Thorlabs' BOA1050P High-Power Booster Optical Amplifier (BOA) is designed to amplify polarized optical signals near 1050 nm. It is an ideal gain medium for implementing wide bandwidth tunable lasers. The semiconductor device is housed in a standard 14-pin butterfly package with FC/APC connectors. Polarization maintaining PM980-XP fiber is used on both input and output sides. An integrated TEC and thermistor provide temperature control to stabilize the gain and optical spectrum.

## **Specifications**

These operating specifications are a consistent set of values, which will yield the specified performance.

CW;  $T_{CHIP} = 25 \, ^{\circ}C$ ;  $T_{CASE} = 0 - 70 \, ^{\circ}C$ 

BOA1050P Specifications					
	Symbol	Min	Typical	Max	
Center Wavelength <sup>a</sup>	λς	1020 nm	1040 nm	1060 nm	
Operating Current	I <sub>OP</sub>	-	-	600 mA	
Optical 3 dB Bandwidth	BW	75 nm	85 nm	-	
Small Signal Gain @ P <sub>IN</sub> = -20 dBm <sup>b,c</sup>	G	24 dB	28 dB	-	
Saturation Output Power (@ -3 dB) <sup>b,c</sup>	P <sub>SAT</sub>	14 dBm	17 dBm	-	
Gain Ripple (rms) <sup>b</sup>	δG	-	-	0.5 dB	
Noise Figure <sup>b,c</sup>	NF	-	7.5 dB	10 dB	
Forward Voltage <sup>b</sup>	$V_{F}$	-	1.7 V	2.4 V	
TEC Operation (Typical/Max @ T <sub>CASE</sub> = 25 °C / 70 °C)					
TEC Current	I <sub>TEC</sub>	-	0.3 A	1.5 A	
TEC Voltage	$V_{TEC}$	-	0.4 V	4.0 V	
Thermistor Resistance	R <sub>TH</sub>	-	10 kΩ	-	



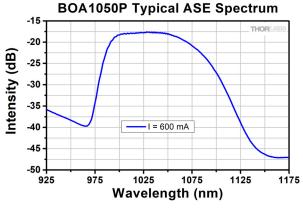
- a. This is the center wavelength of the amplified spontaneous emission (ASE), and is not necessarily the operating wavelength. To yield the specified saturated output power (P<sub>SAT</sub>), a wavelength around 1050 nm was selected as operating wavelength.
- b. At I<sub>OP</sub>
- c. At 1054.7 nm

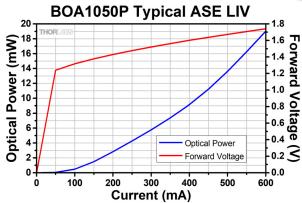
BOA1050P Absolute Maximum Ratings <sup>a</sup>					
Symbol	Min	Max			
$I_{OP}$	•	650 mA			
$P_{Out}$	-	100 mW			
$T_{Chip}$	10 °C	30 °C			
$T_{Case}$	0 °C	70 °C			
	Symbol IOP Pout Tchip	Symbol         Min           IoP         -           Pout         -           T <sub>Chip</sub> 10 °C           T <sub>Case</sub> 0 °C			

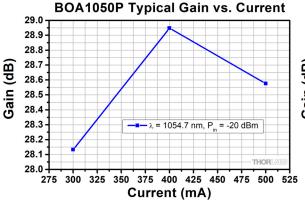
a. Absolute maximum rating specifications should never be exceeded. Operating at or beyond these conditions can permanently damage the amplifier.

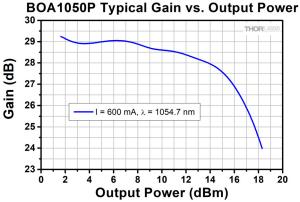
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## **Performance Plots**









# **Drawings**

